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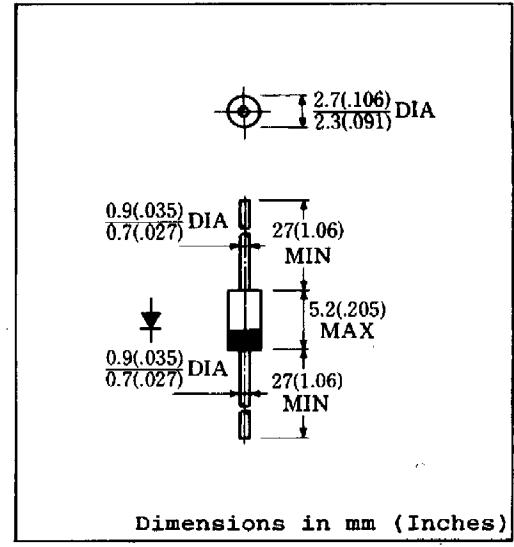
10D1~10D10

SILICON RECTIFIER DIODE

1A/100~1000V

FEATURES

- Miniature Size
- Low Forward Voltage Drop
- Low Reverse Leakage Current
- High Surge Capability



Dimensions in mm (Inches)

Approx. Net Weight: 0.33 Grams

MAXIMUM RATINGS

Voltage Rating	TYPE Symbol	◆10D1	◆10D2	◆10D4	◆10D6	◆10D8	◆10D10	Unit
Repetitive Peak Reverse Voltage	V _{RRM}	100	200	400	600	800	1000	v
Non-Repetitive Peak Reverse Voltage	V _{RSM}	250	400	600	800	1000	1200	v
Electrical Rating	Symbol	Condition			Rating		Unit	
Average Rectified Output Current	I _o	180° sinusoidal wave conduction Ta = 70°C			1.0		A	
RMS Forward Current	I _{F(RMS)}				1.57		A	
Peak One-cycle Forward Surge Current	I _{FSM}	50Hz half sine wave, non-repetitive			50		A	
Operating Frequency	f				1,000		Hz	
Operating Junction Temperature Range	T _{jw}				-40 to 150		°C	
Storage Temperature Range	T _{stg}				-40 to 150		°C	

ELECTRICAL & THERMAL CHARACTERISTICS

Characteristics	Symbol	Test Condition		Max.	Unit
Peak Forward Voltage	V _{FM}	I _{FM} = 1.0A T _j = 25°C		0.9	v
Peak Reverse Current	I _{RM}	V _{RM} = V _{RRM} T _j = 25°C	10D1 ~ 10D2	50	μA
			10D4 ~ 10D10		
Thermal Resistance	R _{th(j-a)}	Junction to Ambient		91	°C/W

NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

